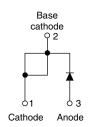


Vishay Semiconductors

Schottky Rectifier, 8 A

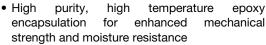




| PRODUCT SUMMARY | | | | | |
|----------------------------------|-------------------|--|--|--|--|
| Package | TO-220AC | | | | |
| I _{F(AV)} | 8 A | | | | |
| V_R | 60 V, 80 V, 100 V | | | | |
| V _F at I _F | 0.58 V | | | | |
| I _{RM} max. | 7 mA at 125 °C | | | | |
| T _J max. | 175 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 7.5 mJ | | | | |

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|---|-------------|-------|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | |
| I _{F(AV)} | Rectangular waveform | 8 | А | | | |
| V_{RRM} | Range | 60 to 100 | V | | | |
| I _{FSM} | t _p = 5 μs sine | 850 | Α | | | |
| V _F | 8 A _{pk} , T _J = 125 °C | 0.58 | V | | | |
| T _J | Range | - 55 to 175 | °C | | | |

| VOLTAGE RATINGS | | | | | | | | |
|--|------------------|------------------|------------------|------------------|------------------|------------------|------------------|-------|
| PARAMETER | SYMBOL | VS- 8TQ060PbF | VS- 8TQ060-N3 | VS- 8TQ080PbF | VS- 8TQ080-N3 | VS- 8TQ100PbF | VS- 8TQ100-N3 | UNITS |
| Maximum DC reverse voltage | V_R | | | | | | | |
| Maximum working peak reverse voltage | V _{RWM} | 60 | 60 | 80 | 80 | 100 | 100 | V |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|--------------------|---|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST COND | ITIONS | VALUES | UNITS | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T _C = 157 °C, rectangular waveform | | 8 | Α | | |
| Maximum peak one cycle non-repetitive surge current | 1 | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 850 | Α | | |
| See fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 230 | A | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH | | 7.50 | mJ | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 0.50 | Α | | |



VS-8TQ...PbF Series, VS-8TQ...-N3 Series

Vishay Semiconductors

| ELECTRICAL SPECIFICATIONS | | | | | | | |
|--|--------------------------------|---|---------------------------------------|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | | |
| | | 8 A | T 05 %0 | 0.72 | V | | |
| Maximum forward voltage drop See fig. 1 | V _{FM} ⁽¹⁾ | 16 A | T _J = 25 °C | 0.88 | | | |
| | | 8 A | T 105 00 | 0.58 | | | |
| | | 16 A | T _J = 125 °C | 0.69 | | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | V _R = rated V _R | 0.55 | mA | | |
| See fig. 2 | 'RM ''' | T _J = 125 °C | VR = rated VR | 7 | IIIA | | |
| Maximum junction capacitance | C _T | V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C | | 500 | pF | | |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 8 | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs | | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|-----------------------------------|--|-------------|------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 55 to 175 | °C | | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation See fig. 4 | 2.0 | °C/W | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | R _{thCS} Mounting surface, smooth and greased | | C/VV | | | |
| Approximate weight | | | 2 | g | | | |
| Approximate weight | | | 0.07 | OZ. | | | |
| Mounting torque minimum | | | 6 (5) | kgf · cm | | | |
| Mounting torque maximum | | | 12 (10) | (lbf · in) | | | |
| | | | 8TQ060 | | | | |
| Marking device | | Case style TO-220AC | 8TQ080 | | | | |
| | | | 8TC | 100 | | | |

Vishay Semiconductors

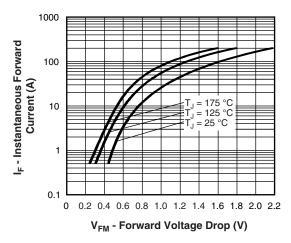


Fig. 1 - Maximum Forward Voltage Drop Characteristics

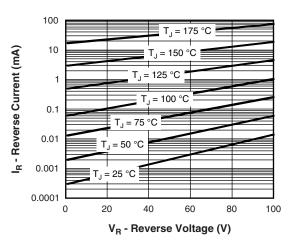


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

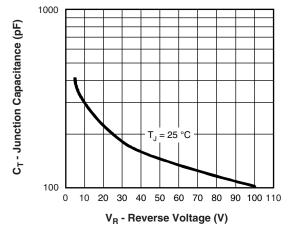


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

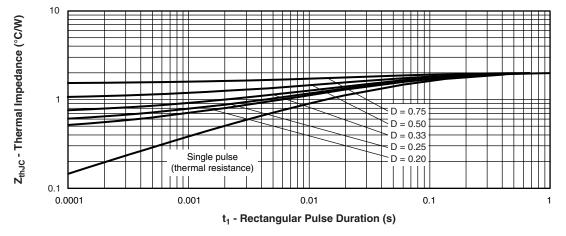


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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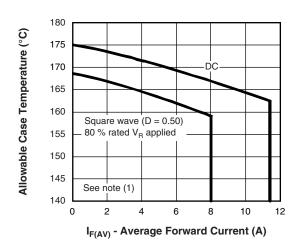


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

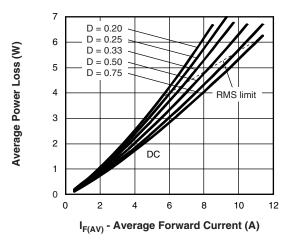


Fig. 6 - Forward Power Loss Characteristics

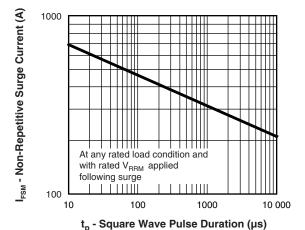


Fig. 7 - Maximum Non-Repetitive Surge Current

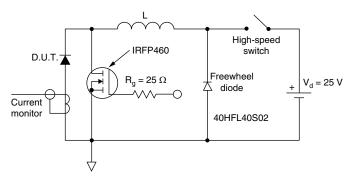


Fig. 8 - Unclamped Inductive Test Circuit

Note

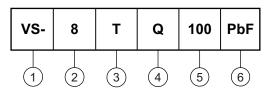
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-8TQ...PbF Series, VS-8TQ...-N3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

- Package:

T = TO-220

- Schottky "Q" series

060 = 60 V 080 = 80 V

5 - Voltage ratings

100 = 100 V

6 - Environmental digit

-l D-110 -----!:---t

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-8TQ060PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-8TQ060-N3 | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-8TQ080PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-8TQ080-N3 | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-8TQ100PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-8TQ100-N3 | 50 | 1000 | Antistatic plastic tube | | | | |

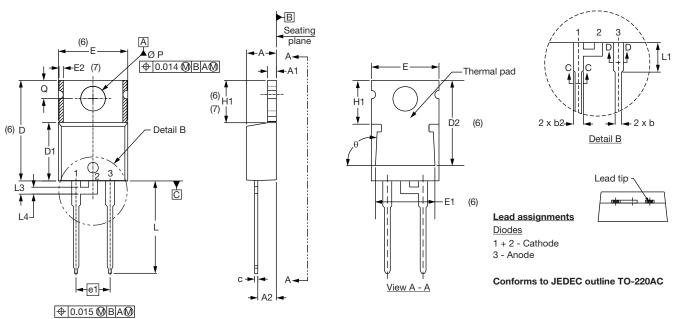
| LINKS TO RELATED DOCUMENTS | | | | | |
|--|--------------|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95221</u> | | | | | |
| Dort marking information | TO-220AC PbF | www.vishay.com/doc?95224 | | | |
| Part marking information | TO-220AC -N3 | www.vishay.com/doc?95068 | | | |



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



| SYMBOL | | IETERS | INC | HES | NOTES |
|----------|-------|--------|-------|-------|-------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |
| Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |

| SYMBOL | MILLIM | IETERS | INCHES | | NOTES |
|----------|--------|--------|--------|-------|-------|
| STINIBUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| E2 | - | 0.76 | - | 0.030 | 7 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| L3 | 1.78 | 2.13 | 0.070 | 0.084 | |
| L4 | 0.76 | 1.27 | 0.030 | 0.050 | 2 |
| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| θ | 90° t | o 93° | 90° t | o 93° | |
| | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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Vishay

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